



GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz

Typical Applications

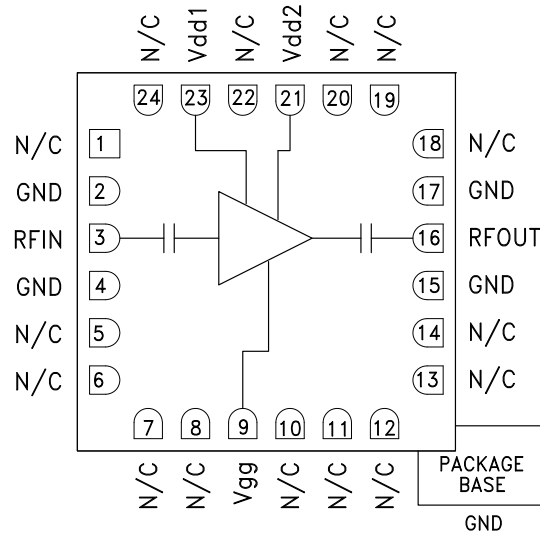
The HMC609LC4 is ideal for:

- Fixed Microwave
- Test & Measurement Equipment
- Radar & Sensors
- Military & Space

Features

- Excellent Gain Flatness: ± 0.4 dB
- High Gain: 20 dB
- Low Noise Figure: 3.5 dBm
- Output IP3: +36.5 dBm
- 50 Ohm Matched & DC Blocked RF I/Os
- RoHS Compliant 4 x 4 mm SMT Package

Functional Diagram



General Description

The HMC609LC4 is a GaAs PHEMT MMIC Low Noise Amplifier (LNA) which operates from 2 to 4 GHz. The HMC609LC4 features extremely flat performance characteristics including 20 dB of small signal gain, 3.5 dB of noise figure and output IP3 of +36.5 dBm across the operating band. This 50 Ohm matched amplifier does not require any external matching components. The HMC609LC4 is compatible with high volume surface mount manufacturing techniques, and the RF I/Os are DC blocked for further ease of integration.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd1} = V_{dd2} = +6\text{V}$, $I_{dd1} + I_{dd2} = 170\text{mA}$ [1]

| Parameter | Min. | Typ. | Max. | Units |
|---|-------|-------|------|-------|
| Frequency Range | 2 - 4 | | | GHz |
| Gain | 17 | 20 | | dB |
| Gain Variation Over Temperature | | 0.015 | 0.02 | dB/°C |
| Noise Figure | | 3.5 | 5.5 | dB |
| Input Return Loss | | 17 | | dB |
| Output Return Loss | | 15 | | dB |
| Output Power for 1 dB Compression (P1dB) | 18.5 | 21.5 | | dBm |
| Saturated Output Power (P _{sat}) | | 23 | | dBm |
| Output Third Order Intercept (IP3) | | 36.5 | | dBm |
| Supply Current (I _{dd1} + I _{dd2}) | | 170 | 220 | mA |

Adjust V_{gg} between -1.5V to -0.5V (Typical -0.9V) to achieve total drain bias of 170mA

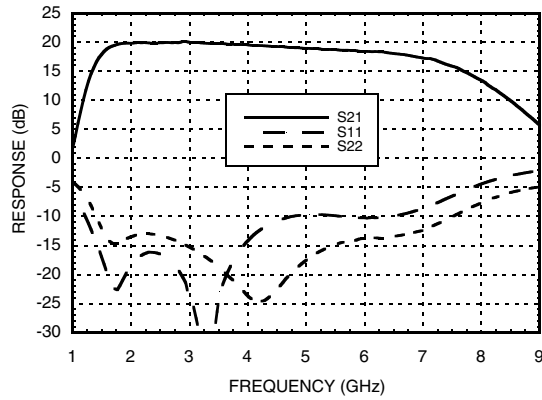
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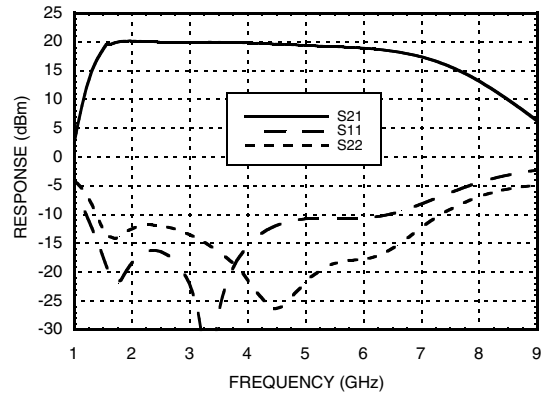


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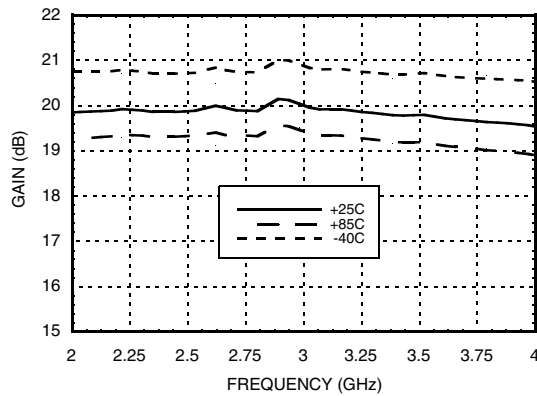
Broadband Gain & Return Loss^[1]



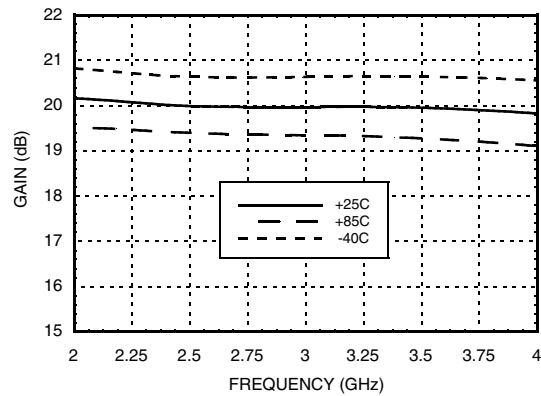
Broadband Gain & Return Loss^[2]



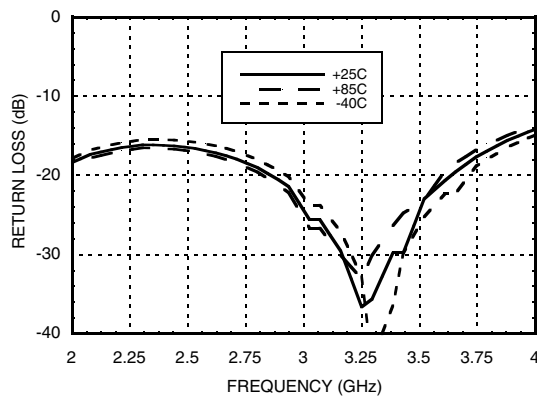
Gain vs. Temperature^[1]



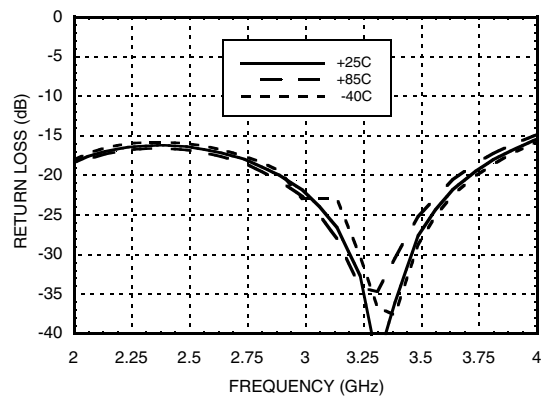
Gain vs. Temperature^[2]



Input Return Loss vs. Temperature^[1]



Input Return Loss vs. Temperature^[2]



[1] V_{DD} = 6V [2] V_{DD} = 5V

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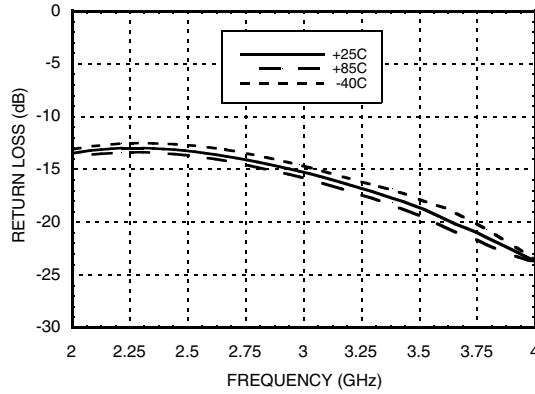
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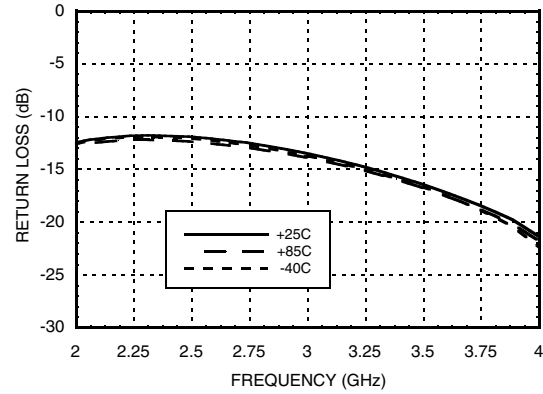
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AMPLIFIERS - LOW NOISE- SMT

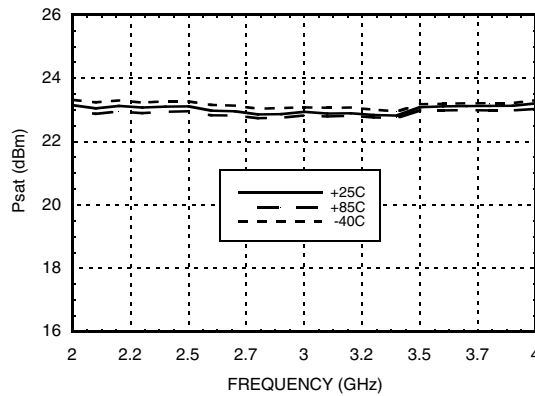
Output Return Loss vs. Temperature [1]



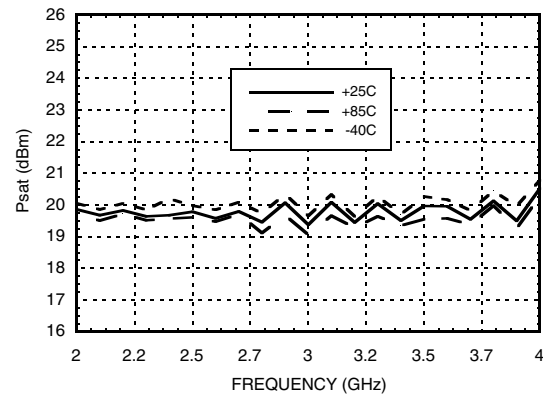
Output Return Loss vs. Temperature [2]



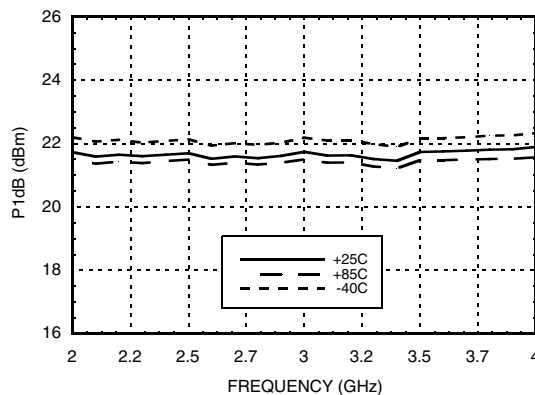
Psat vs. Temperature [1]



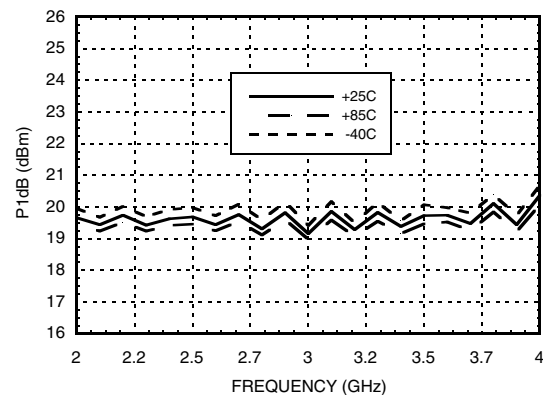
Psat vs. Temperature [2]



P1dB vs. Temperature [1]



P1dB vs. Temperature [2]



[1] Vdd = 6V

[2] Vdd = 5V

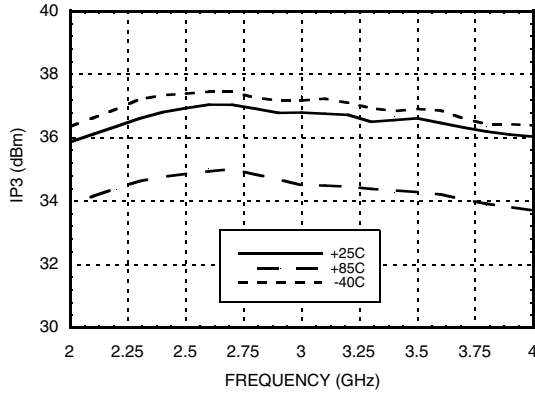
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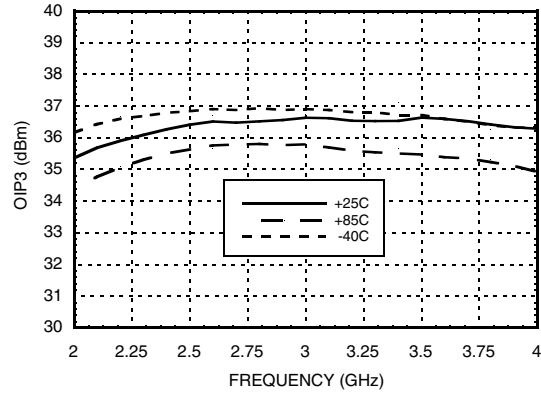


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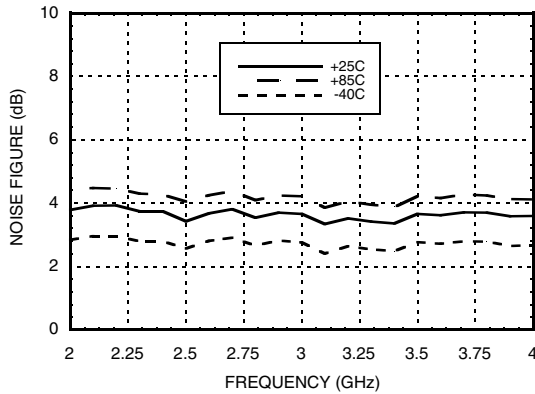
Output IP3 vs. Temperature [1]



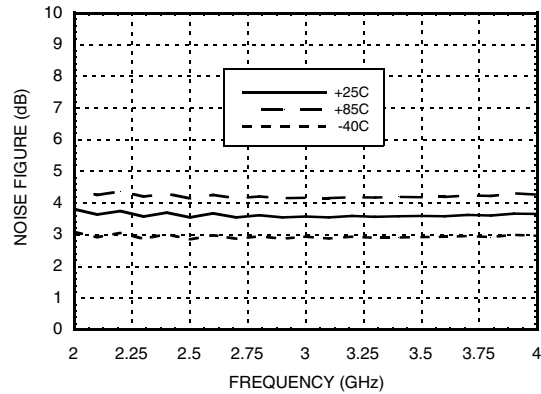
Output IP3 vs. Temperature [2]



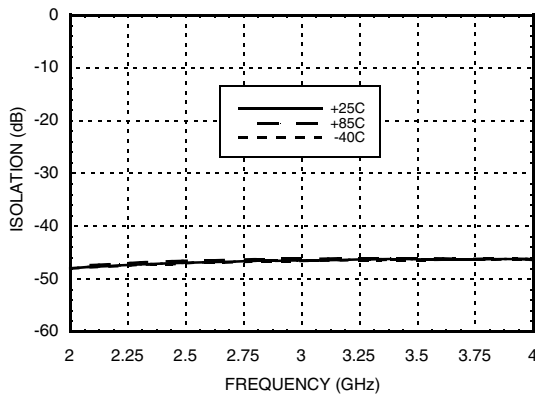
Noise Figure vs. Temperature [1]



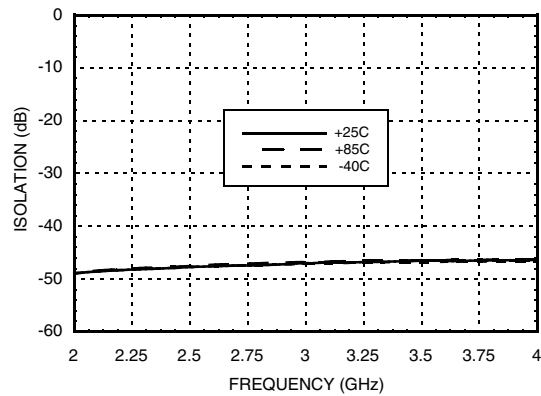
Noise Figure vs. Temperature [2]



Reverse Isolation vs. Temperature [1]



Reverse Isolation vs. Temperature [2]

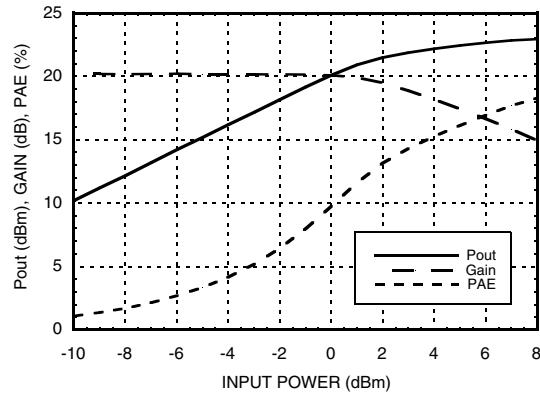


[1] Vdd = 6V

[2] Vdd = 5V

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**GaAs PHEMT MMIC LOW NOISE
AMPLIFIER, 2 - 4 GHz**
Power Compression @ 3 GHz

Absolute Maximum Ratings

| | |
|--|----------------|
| Drain Bias Voltage (V _{dd}) | 7 Vdc |
| RF Input Power (RFIN)(V _{dd} = +6.0 Vdc) | +15 dBm |
| Channel Temperature | 175 °C |
| Continuous Pdiss (T= 85 °C) (derate 16.7 mW/°C above 85 °C) | 1.1 W |
| Thermal Resistance (channel to ground paddle) | 60 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |

Typical Supply Current vs. V_{dd}

| V _{dd} (V) | I _{dd} (mA) |
|---------------------|----------------------|
| +5.5 | 160 |
| +6.0 | 170 |
| +6.5 | 180 |

Note: Amplifier will operate over full voltage range shown above

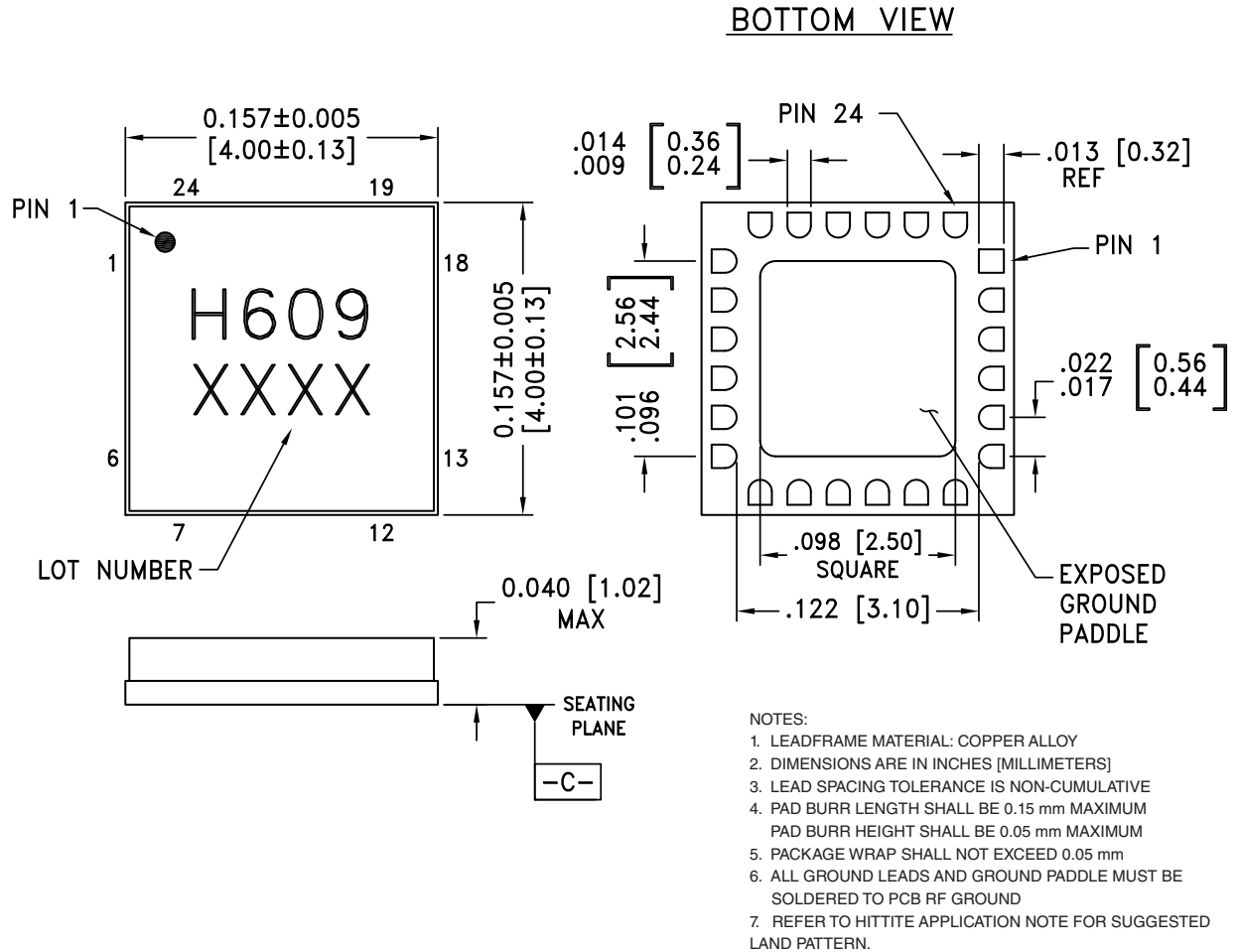


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**



GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz

Outline Drawing



Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[2] |
|-------------|-----------------------|------------------|---------------------|--------------------------------|
| HMC609LC4 | Alumina, White | Gold over Nickel | MSL3 ^[1] | H609 XXXX |

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



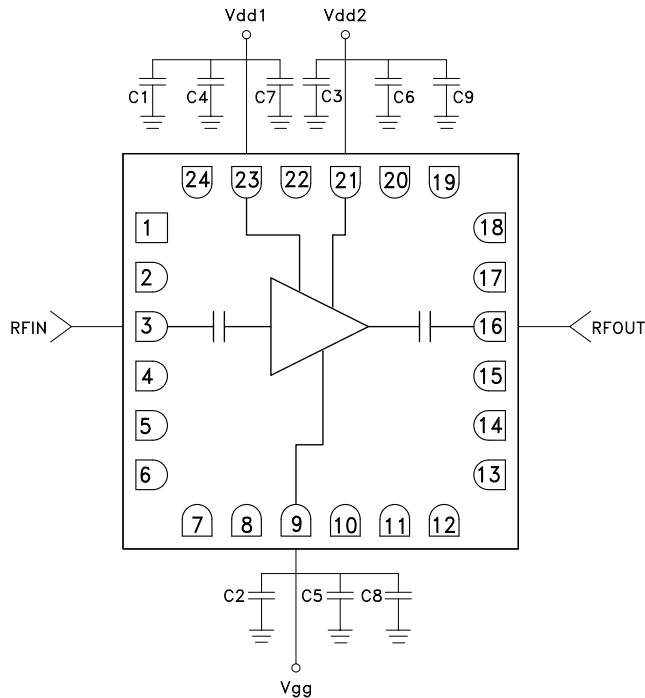
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Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|------------------------------------|------------|---|---------------------|
| 1, 5 - 8, 10 - 24, 18 - 20, 22, 24 | N/C | This pin may be connected to RF/DC ground. Performance will not be affected. | |
| 2, 4, 15, 17 | GND | These pins and package bottom must also be connected to RF/DC ground. | |
| 3 | RFIN | This pin is AC coupled and matched to 50 Ohms. | |
| 9 | Vgg | Gate supply voltage for the amplifier. (External bypass capacitors are required.) | |
| 16 | RFOUT | This pin is AC coupled and matched to 50 Ohms. | |
| 21, 23 | Vdd1, Vdd2 | Power Supply Voltage for the amplifier. (External bypass capacitors are required.). | |

Application Circuit

| Component | Value |
|-----------|----------|
| C1 - C3 | 100 pF |
| C4 - C6 | 1,000 pF |
| C7 - C9 | 2.2 μF |



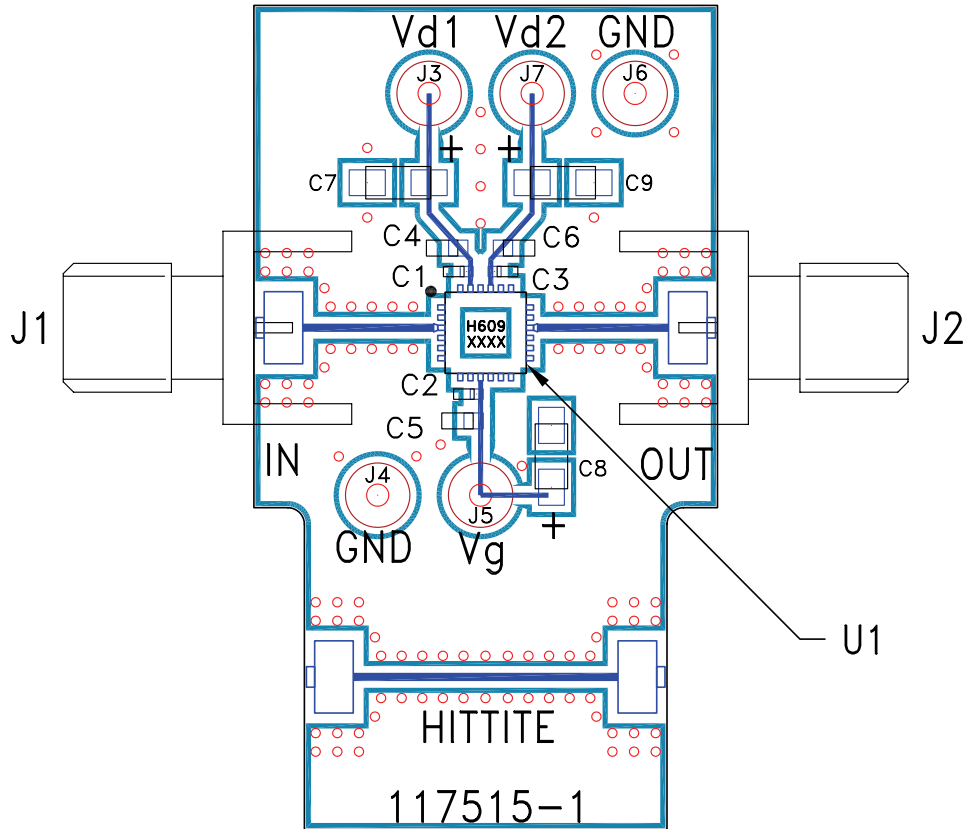
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Evaluation PCB



List of Materials for Evaluation PCB 117510 [1]

| Item | Description |
|---------|-----------------------------|
| J1 - J2 | PCB Mount SMA Connector |
| J3 - J7 | DC Pin |
| C1 - C3 | 100 pF Capacitor, 0402 Pkg. |
| C4 - C6 | 1000pF Capacitor, 0603 Pkg. |
| C7 - C9 | 2.2 μF Capacitor, Tantalum |
| U1 | HMC609LC4 Amplifier |
| PCB [2] | 1117515 Evaluation PCB |

[1] Reference this number when ordering complete evaluation PCB
 [2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.